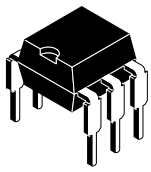
Optocoupler with Photodarlington Output

Description

The 4N32 and 4N33 consist of a photodarlington optically coupled to a gallium arsenide infrared-emitting diode in a 6-lead plastic dual inline package.
The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.



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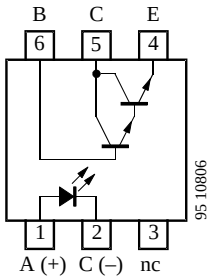
Applications

Galvanically separated circuits, non-interacting switches



Features

- High isolation resistance
- **U**nderwriters **L**aboratory (UL) 1577 recognized, file number E-76222
- Low coupling capacity typical 0.3 pF
- High **C**urrent **T**ransfer **R**atio (CTR)
- Low temperature coefficient of CTR
- Coupling System A

Order Instruction

Ordering Code	CTR Ranking	Remarks
4N32	> 500%	
4N33	> 500%	

Absolute Maximum Ratings

Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \le 10$ µs	I_{FSM}	3	A
Power dissipation	$T_{amb} \le 25$˚C	P_V	100	mW
Junction temperature		T_j	125	˚C

Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector base voltage		V_{CBO}	50	V
Collector emitter voltage		V_{CEO}	30	V
Emitter collector voltage		V_{ECO}	5	V
Collector current		I_C	150	mA
Peak collector current	$t_p/T = 0.5$, $t_p \le 10$ ms	I_{CM}	200	mA
Power dissipation	$T_{amb} \le 25$˚C	P_V	150	mW
Junction temperature		T_j	125	˚C

Coupler

Parameter	Test Conditions	Symbol	Value	Unit
Isolation test voltage (RMS)	t = 1 min	V_{IO}	3.75	kV
Total power dissipation	$T_{amb} \le 25$˚C	P_{tot}	250	mW
Ambient temperature range		T_{amb}	–55 to +100	˚C
Storage temperature range		T_{stg}	–55 to +125	˚C
Soldering temperature	2 mm from case, t ≤ 10 s	T_{sd}	260	˚C

Electrical Characteristics (T_{amb} = 25°C)

Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	I_F = 50 mA	V_F		1.25	1.5	V
Junction capacitance	V_R = 0, f = 1 MHz	C_j		50		pF

Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector base voltage	I_C = 100 µA	V_{CBO}	50			V
Collector emitter voltage	I_C = 1mA	V_{CEO}	30			V
Emitter collector voltage	I_C = 100 µA	V_{ECO}	5			V
Collector dark current	V_{CE} = 10 V, I_F = 0, E = 0	I_{CEO}			100	nA

Coupler

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Isolation test voltage (RMS)	f = 50 Hz, t = 2 s	V_{IO} [1)]	3.75			kV
Isolation resistance	V_{IO} = 1000 V, 40% relative humidity	R_{IO} [1)]		10^{12}		Ω
Collector emitter saturation voltage	I_F = 8 mA, I_C = 2 mA	V_{CEsat}			1	V
Cut-off frequency	I_F = 2 mA, V_{CE} = 10 V, R_L = 100 Ω	f_c		30		kHz
Coupling capacitance	f = 1 MHz	C_k		0.3		pF

1) Related to standard climate23/50 DIN 50014

Current Transfer Ratio (CTR)

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
I_C/I_F	V_{CE} = 10 V, I_F = 10 mA, t_p/T = 0.01, t_p = 0.3 ms	4N32, 4N33	CTR	5			

Switching Characteristics

Parameter	Test Conditions	Symbol	Typ.	Unit
Turn-on time	V_S = 10 V, I_C = 50 mA, R_L = 100 Ω (see figure 1)	t_{on}	50	µs
Turn-off time		t_{off}	40	µs

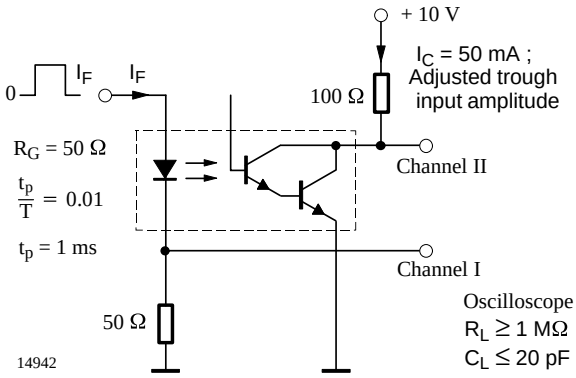
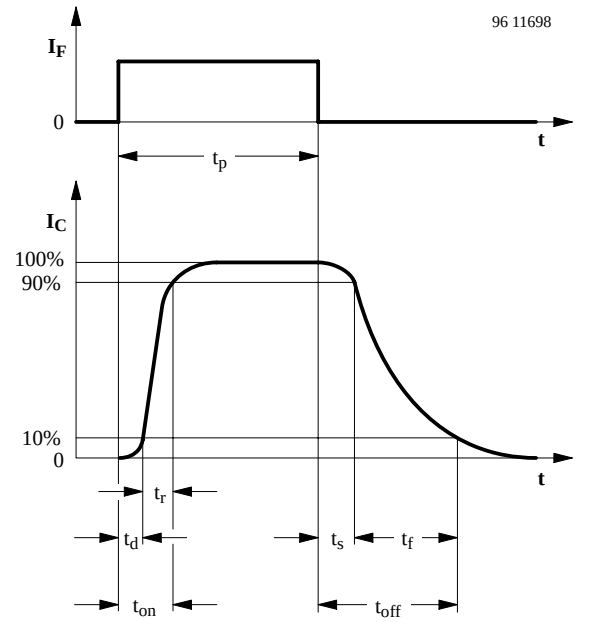


Figure 1. Test circuit, non-saturated operation



t_p	pulse duration	t_s	storage time
t_d	delay time	t_f	fall time
t_r	rise time	t_{off} (= t_s + t_f)	turn-off time
t_{on} (= t_d + t_r)	turn-on time		

Figure 2. Switching times

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

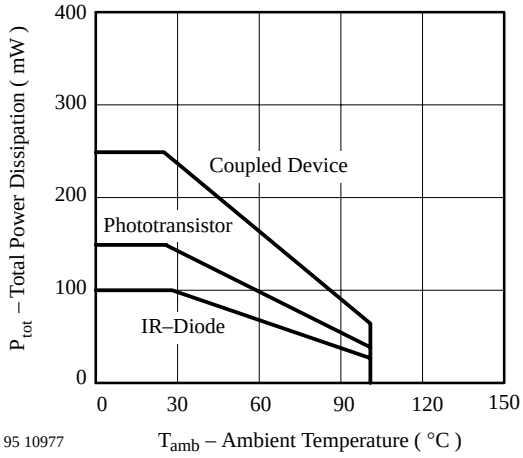


Figure 3. Total Power Dissipation vs. Ambient Temperature

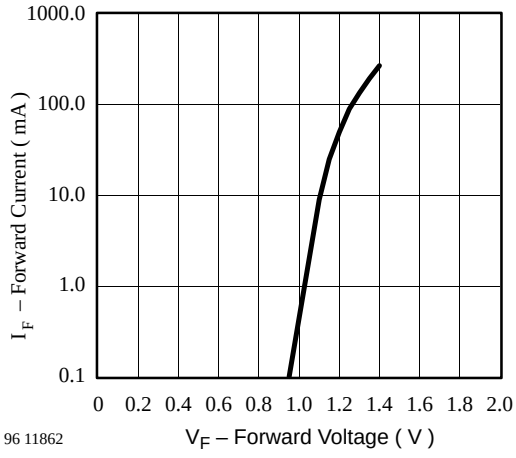


Figure 4. Forward Current vs. Forward Voltage

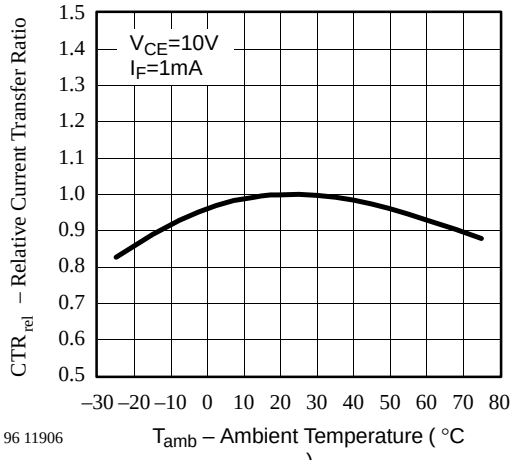


Figure 5. Relative Current Transfer Ratio vs. Ambient Temperature

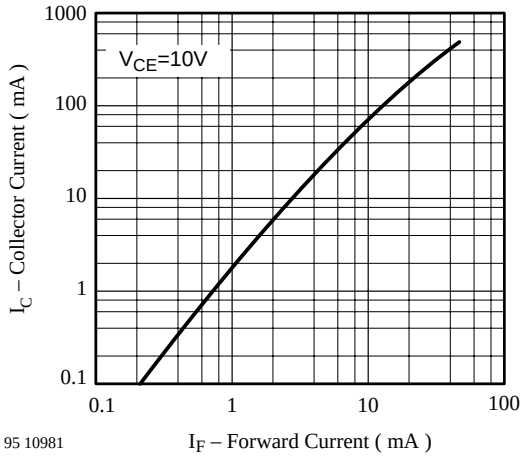


Figure 8. Collector Current vs. Forward Current

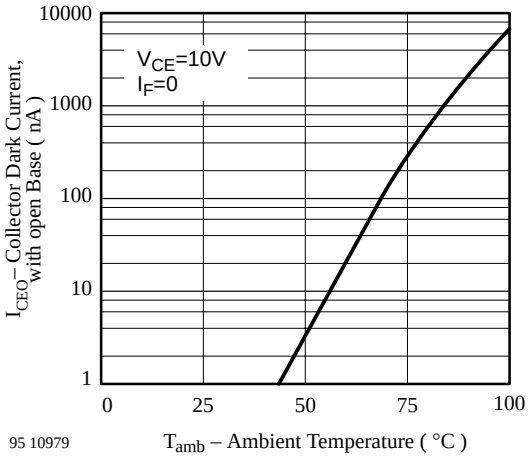


Figure 6. Collector Dark Current vs. Ambient Temperature

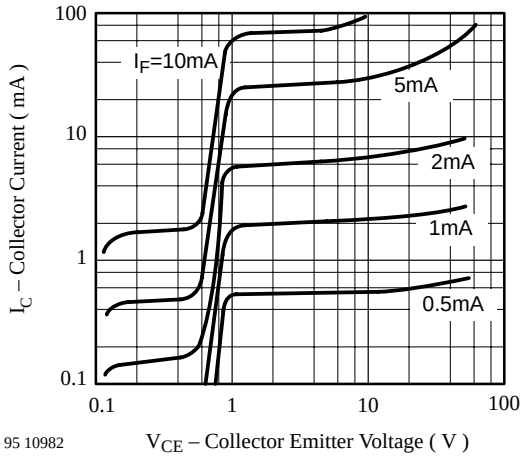


Figure 9. Collector Current vs. Collector Emitter Voltage

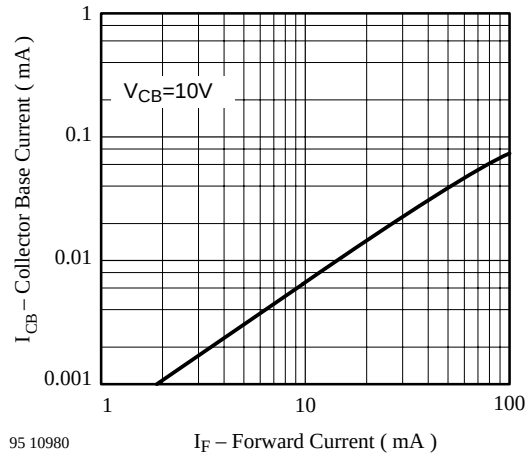


Figure 7. Collector Base Current vs. Forward Current

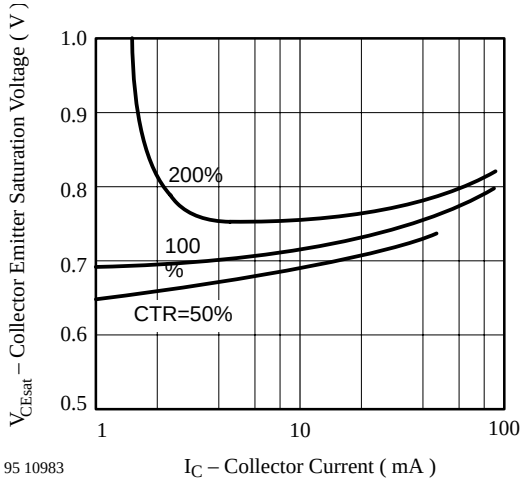


Figure 10. Collector Emitter Saturation Voltage vs. Collector Current

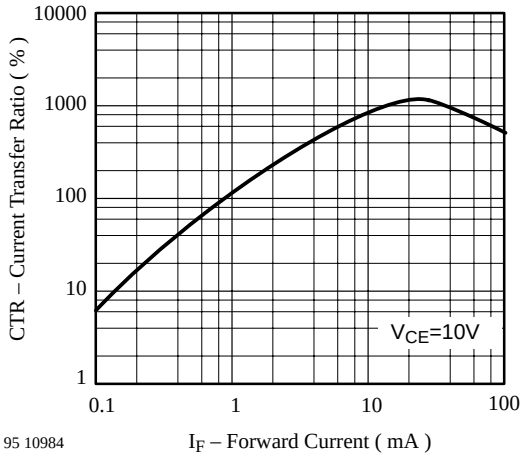


Figure 11. Current Transfer Ratio vs. Forward Current

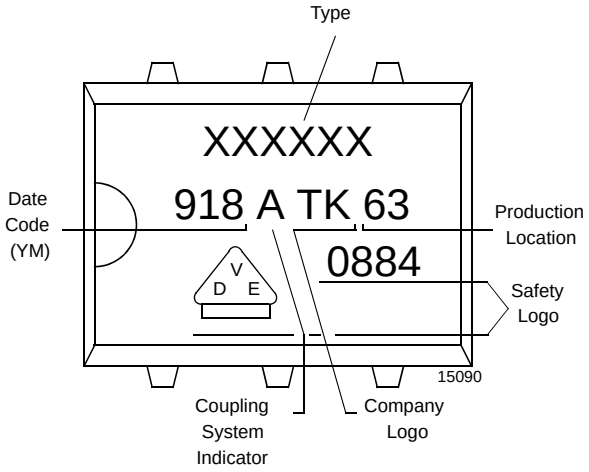


Figure 12. Marking example

Dimensions of 4N32/ 4N33 in mm